



3A, 50V - 1000V Surface Mount Fast Recovery Rectifier

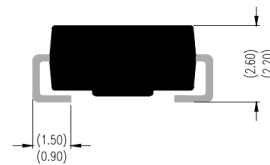
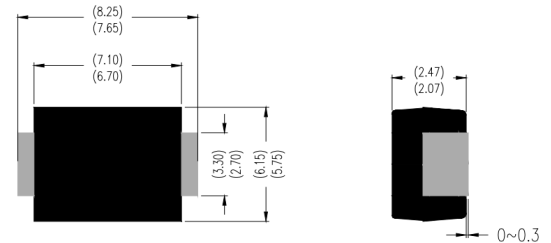
Features

- Glass passivated chip junction
- Ideal for automated placement
- Fast switching for high efficiency
- High surge current capability
- Comply with RoHS standard, halogen-free

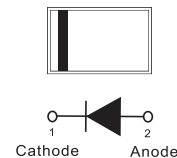
Mechanical Data

- Case: SMC/DO-214AB
- Polarity: As marked
- Epoxy: UL 94V-0 rate flame retardant
- Mounting Position : Any

SMC/DO-214AB



Unit : inch(mm)



Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	RS3AC	RS3BC	RS3DC	RS3GC	RS3JC	RS3KC	RS3MC	Unit
Repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Forward current	$I_{F(AV)}$	3							A
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	100							A
Junction temperature	T_J	- 55 to +150							$^{\circ}\text{C}$
Storage temperature	T_{STG}	- 55 to +150							$^{\circ}\text{C}$

Thermal Performance ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	TYP	Unit
Junction-to-lead thermal resistance per diode	$R_{\theta JL}$	15	$^\circ\text{C/W}$
Junction-to-ambient thermal resistance per diode	$R_{\theta JA}$	50	$^\circ\text{C/W}$

Electrical Specifications ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	TYP	MAX	Unit
Forward voltage per diode ⁽¹⁾	$I_F = 3\text{A}$, $T_J = 25^\circ\text{C}$	V_F	-	1.3	V
Reverse current @ rated V_R per diode ⁽²⁾	$T_J = 25^\circ\text{C}$	I_R	-	10	μA
	$T_J = 125^\circ\text{C}$		-	250	μA
Reverse recovery time	$I_F=0.5\text{A}$, $I_R=1.0\text{A}$ $I_{RR}=0.25\text{A}$	t_{rr}	-	150	ns
			-	250	ns
			-	500	ns
			-		

Notes:

1. Pulse test with $PW=0.3\text{ ms}$
2. Pulse test with $PW=30\text{ ms}$

Characteristics Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

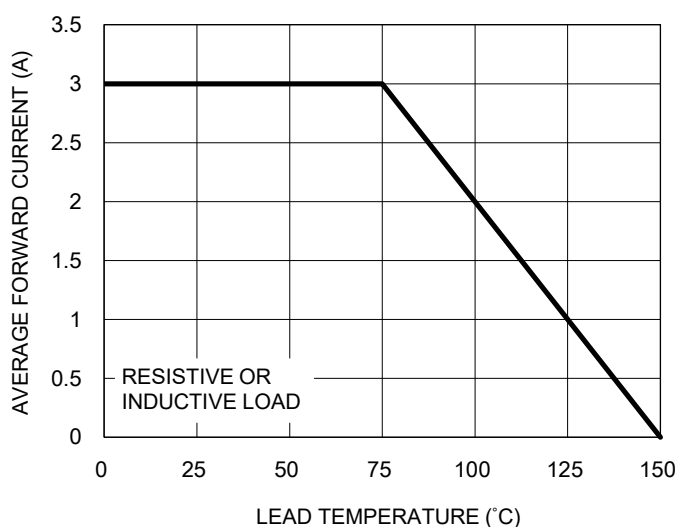
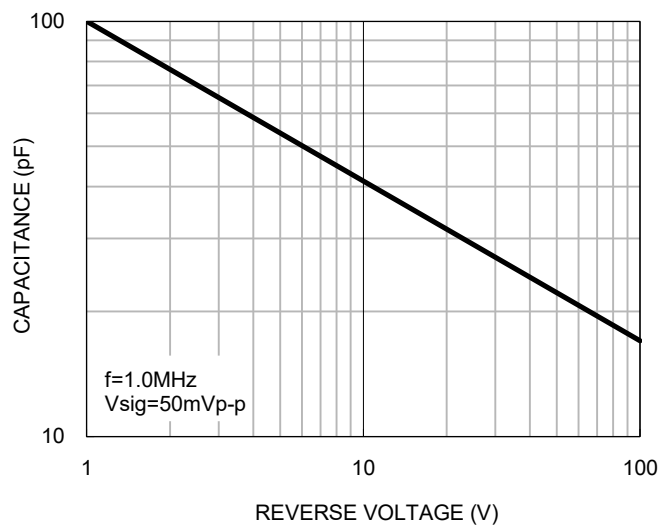


Fig.2 Typical Junction Capacitance





Characteristics Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)

Fig.3 Typical Reverse Characteristics

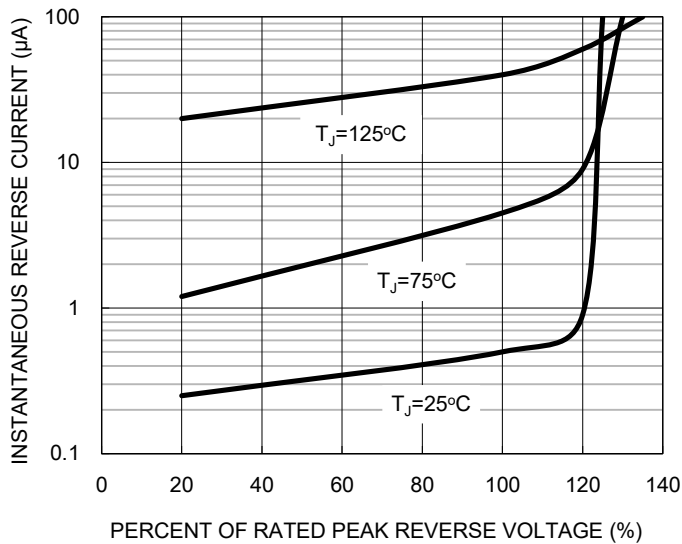


Fig.4 Typical Forward Characteristics

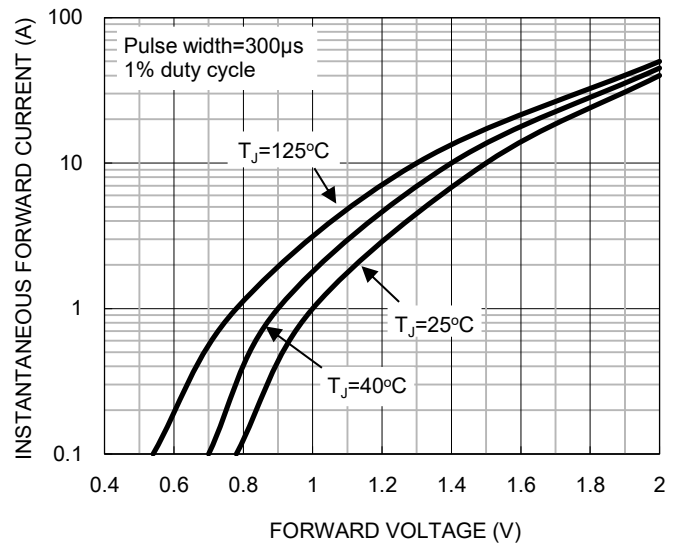


Fig.5 Maximum Non-repetitive Forward Surge Current

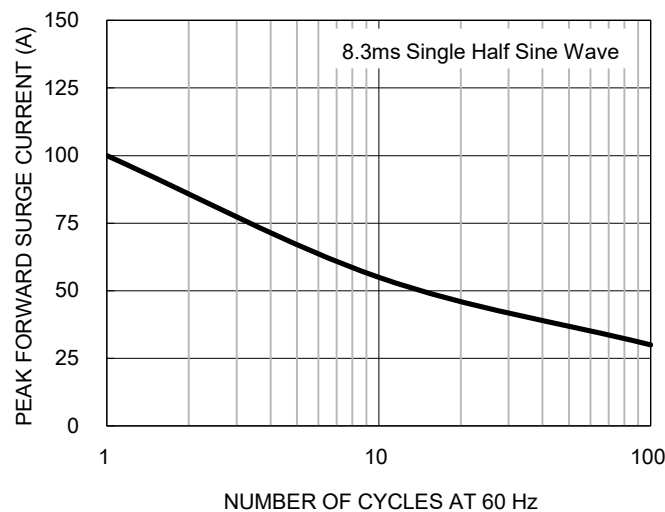


Fig.6 Reverse Recovery Time Characteristic And Test Circuit Diagram

